

DMP2305UVT
20V P-CHANNEL ENHANCEMENT MODE MOSFET
Product Summary

$V_{(BR)DSS}$	Max $R_{DS(on)}$ (Note 6)	Max I_D $T_A = 25^\circ\text{C}$
-20V	60m Ω @ $V_{GS} = -4.5\text{V}$	-4.23A
	90m Ω @ $V_{GS} = -2.5\text{V}$	-3.49A
	113m Ω @ $V_{GS} = -1.8\text{V}$	-3.11A

Description

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Motor Control
- Power management functions
- Analog Switch

Features

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

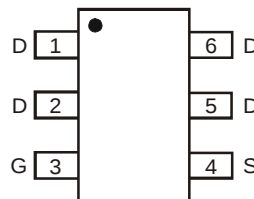
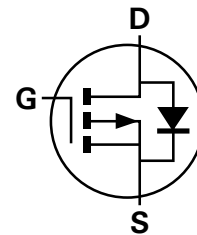
Mechanical Data

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 
- Weight: 0.0013 grams (approximate)

TSOT26



Top View

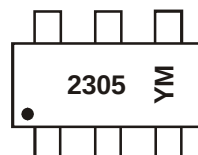

 Top View
Pin-Out


Equivalent Circuit

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMP2305UVT-7	2305	7	8	3,000
DMP2305UVT-13	2305	13	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information


2305 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: Y = 2011)
 M = Month (ex: 9 = September)

Date Code Key

Year	2011	2012	2013	2014	2015	2016	2017
Code	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 6) V _{GS} = -4.5V	Steady State	T _A = +25°C	I _D	-4.23	A
		T _A = +70°C		-2.98	
Continuous Drain Current (Note 6) V _{GS} = -2.5V	Steady State	T _A = +25°C	I _D	-3.49	A
		T _A = +70°C		-2.79	
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	-4.23	A
Pulsed Drain Current (10μs pulse, duty cycle = 1%)			I _{DM}	-16	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation	(Note 5)	P _D	1.25	W
	(Note 6)		1.64	
Thermal Resistance, Junction to Ambient	(Note 5)	R _{θJA}	100	°C/W
	(Note 6)		76	
Thermal Resistance, Junction to Case	(Note 6)	R _{θJC}	14	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to 150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

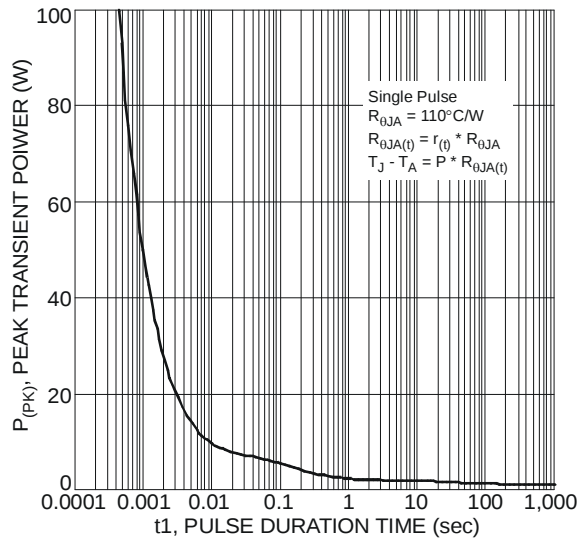


Figure 1 Single Pulse Maximum Power Dissipation

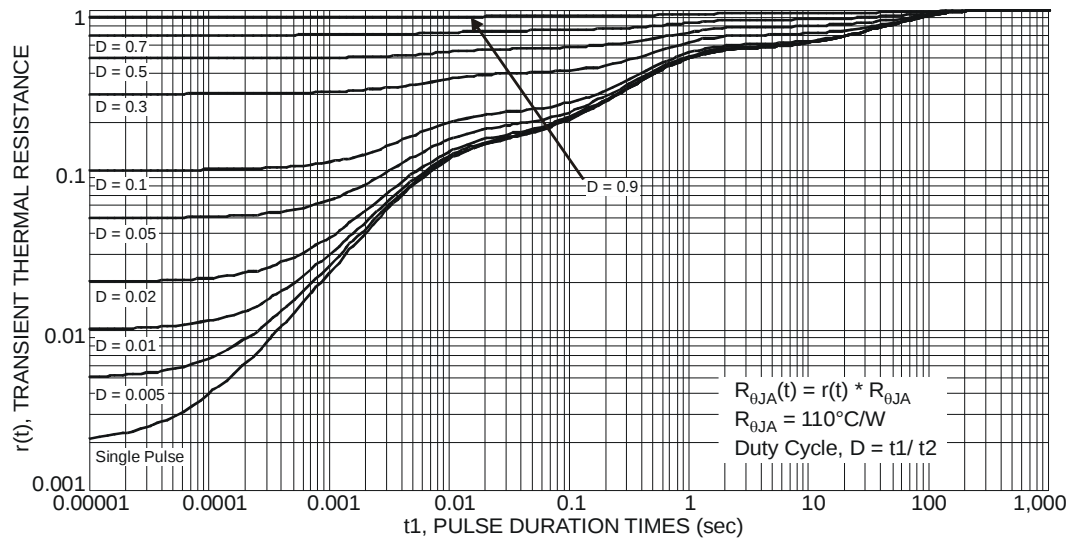


Figure 2 Transient Thermal Resistance

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±8V, V _{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.5	—	-0.9	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(on)}	—	45	60	mΩ	V _{GS} = -4.5V, I _D = -4.2A
		—	60	90		V _{GS} = -2.5V, I _D = -3.4A
		—	87	113		V _{GS} = -1.8V, I _D = -2.0A
Forward Transfer Admittance	Y _{fs}	—	9	—	S	V _{DS} = -5V, I _D = -4A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	—	727	—	pF	V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	69	—		
Reverse Transfer Capacitance	C _{rss}	—	64	—		
Gate Resistance	R _G	—	23	—	Ω	V _{GS} = 0V, V _{DS} = 0V, f = 1.0MHz
Total Gate Charge	Q _g	—	7.6	—	nC	V _{GS} = -4.5V, V _{DS} = -4V, I _D = -3.5A
Gate-Source Charge	Q _{gs}	—	1.4	—		
Gate-Drain Charge	Q _{gd}	—	1.2	—		
Turn-On Delay Time	t _{D(on)}	—	14.0	—	ns	V _{DS} = -4V, V _{GS} = -4.5V, R _L = 4Ω, R _G = 6Ω, I _D = -1A
Turn-On Rise Time	t _r	—	13.0	—		
Turn-Off Delay Time	t _{D(off)}	—	53.8	—		
Turn-Off Fall Time	t _f	—	23.2	—		

Notes: 7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

DMP2305UVT

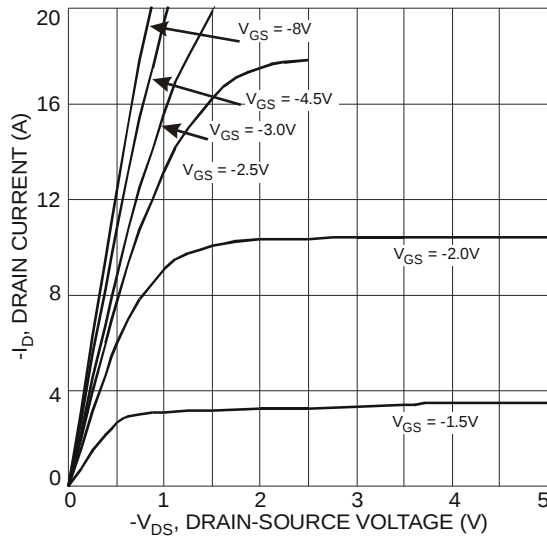


Figure 3 Typical Output Characteristic

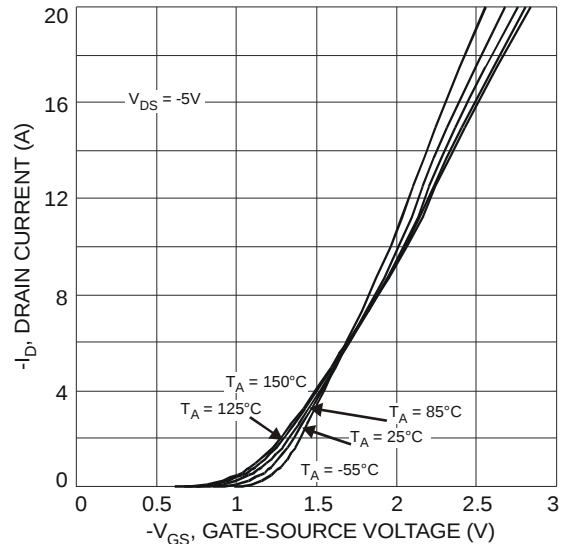


Figure 4 Typical Transfer Characteristic

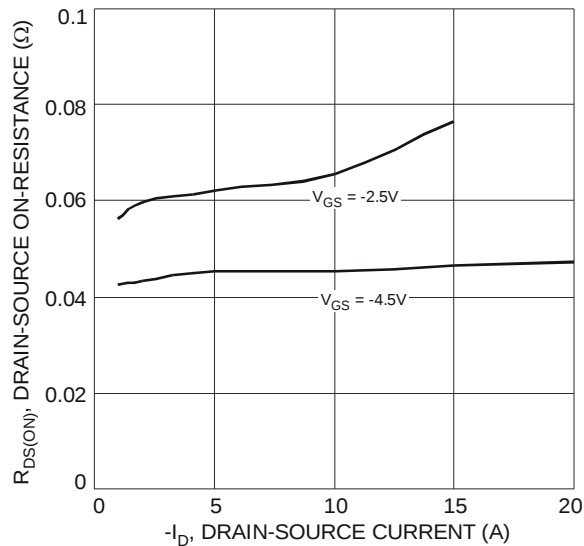


Figure 5 Typical On-Resistance vs. Drain Current and Gate Voltage

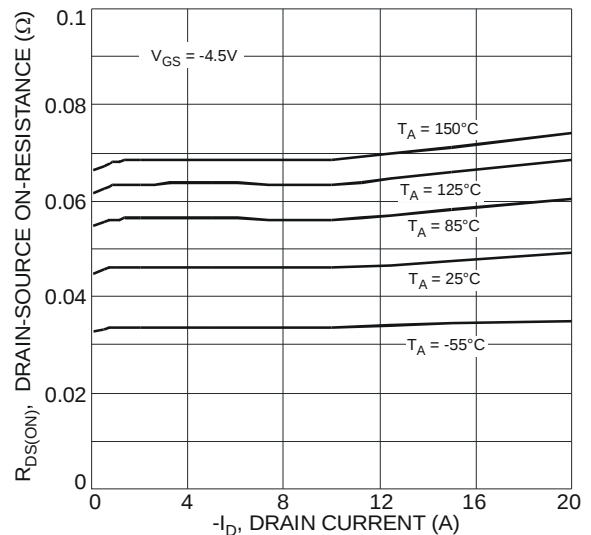


Figure 6 Typical On-Resistance vs. Drain Current and Temperature

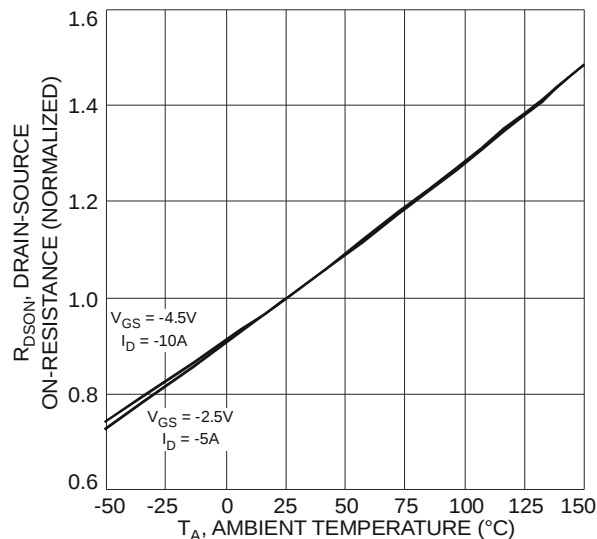


Figure 7 On-Resistance Variation with Temperature

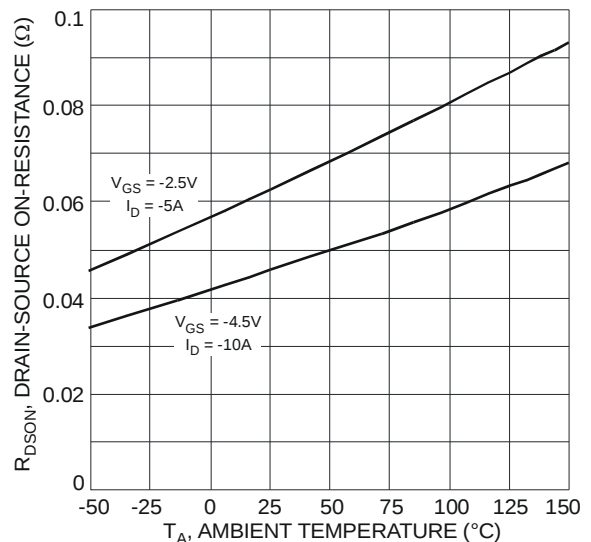


Figure 8 On-Resistance Variation with Temperature

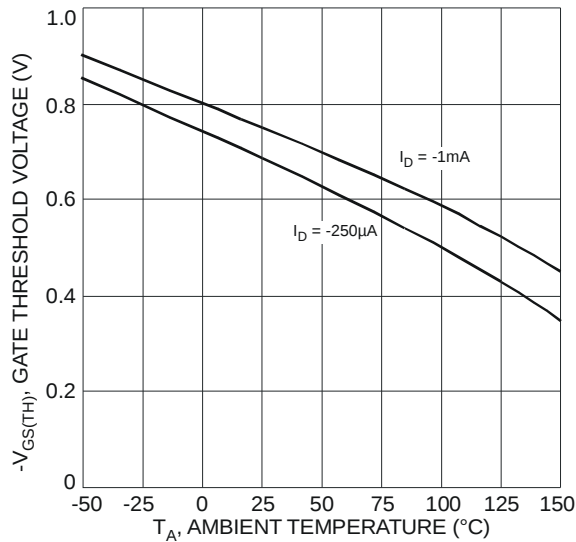


Figure 9 Gate Threshold Variation vs. Ambient Temperature

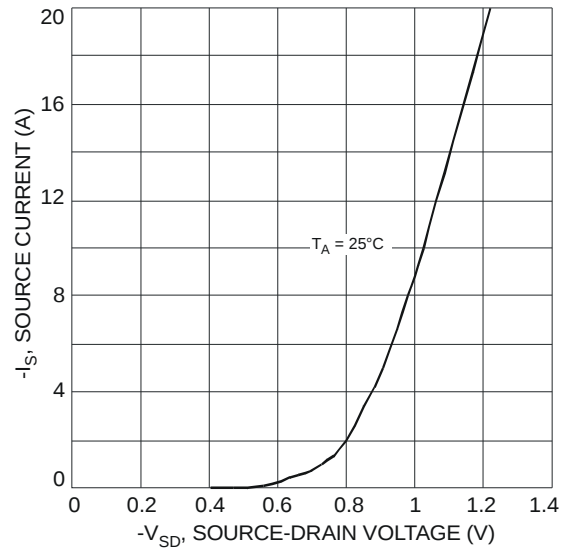


Figure 10 Diode Forward Voltage vs. Current

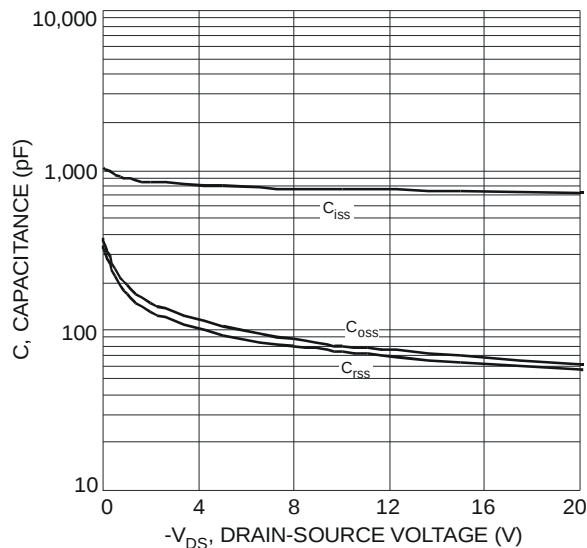


Figure 11 Typical Total Capacitance

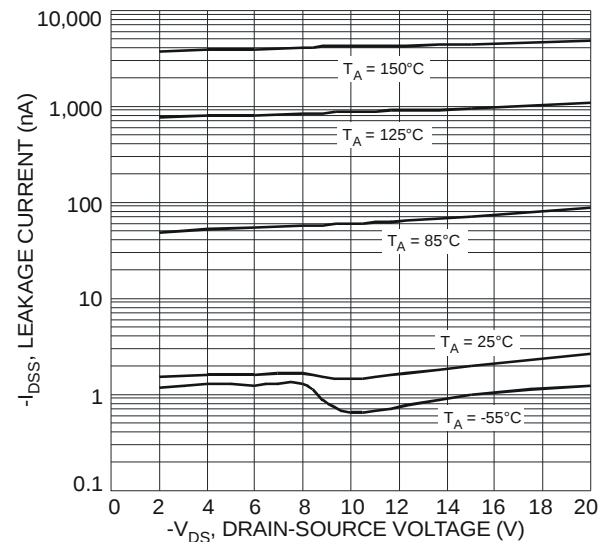
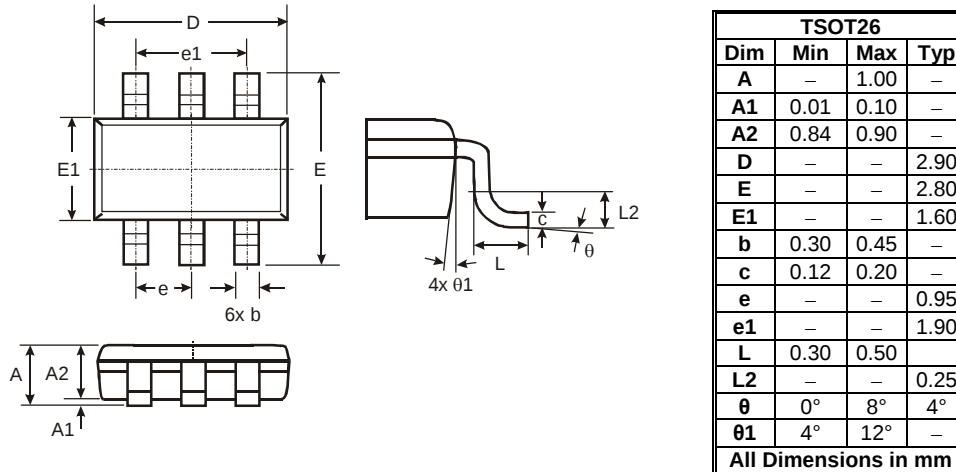


Figure 12 Typical Leakage Current vs. Drain-Source Voltage

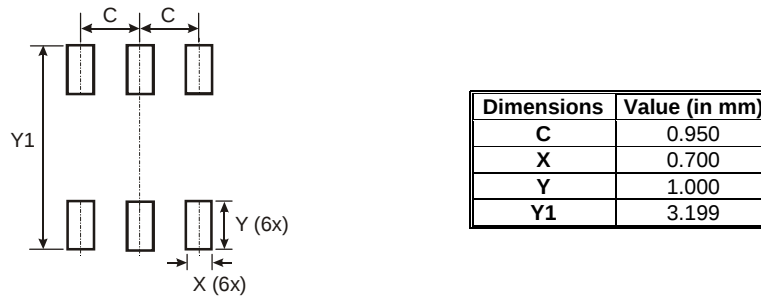
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



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